



30V P-Channel Enhancement Mode MOSFET - ESD Protected

Voltage -30 V Current -0.5A

Features

- RDS(ON), VGS@-4.5V, ID@-0.5A<390mΩ
- RDS(ON), VGS@-2.5V, ID@-0.3A<560mΩ
- RDS(ON), VGS@-1.8V, ID@-0.1A<990mΩ
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

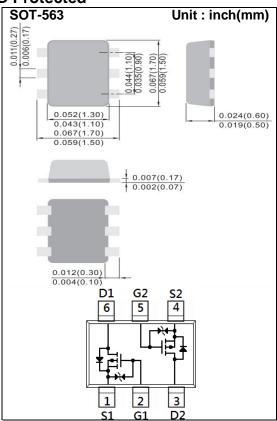
Mechanical Data

• Case: SOT-563 Package

Terminals: Solderable per MIL-STD-750, Method 2026

Approx. Weight: 0.00009 ounces, 0.0026 grams

Marking: X05



Maximum Ratings and Thermal Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-30	V
Gate-Source Voltage		V_{GS}	<u>+</u> 8	V
Continuous Drain Current		I _D	-0.5	А
Pulsed Drain Current		I _{DM}	-2.0	Α
Power Dissipation	T _a =25°C	P _D	300	mW
	Derate above 25°C		2.4	mW/°C
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C
Typical Thermal resistance - Junction to Ambient (Note 3)		$R_{\theta JA}$	417	°C/W





Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS		
Static								
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V, I _D =-250uA	-30	-	-	V		
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-250uA$	-0.5	-0.98	-1.3	V		
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-0.5A	-	318	390	mΩ		
		V _{GS} =-2.5V, I _D =-0.3A	-	427	560			
		V _{GS} =-1.8V, I _D =-0.1A	1	853	990			
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V, V _{GS} =0V	-	-0.01	-1	uA		
Gate-Source Leakage Current	I_{GSS}	V _{GS} = <u>+</u> 8V, V _{DS} =0V	-	<u>+</u> 3.2	<u>+</u> 10	uA		
Dynamic								
Total Gate Charge	Q_g	V _{DS} =-15V, I _D =-0.5A, V _{GS} =-4.5V ^(Note 1,2)	-	1.6	-	nC		
Gate-Source Charge	Q_gs		-	0.5	-			
Gate-Drain Charge	Q_{gd}		-	0.3	-			
Input Capacitance	Ciss	V _{DS} =-15V, V _{GS} =0V,	-	137	-	pF		
Output Capacitance	Coss		-	23	-			
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	10	-			
Switching								
Turn-On Delay Time	td _(on)	\\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \	-	11	-			
Turn-On Rise Time	tr	$\begin{array}{c} V_{DD}{=}{-}15V,\ I_{D}{=}{-}0.5A, \\ V_{GS}{=}{-}4.5V, \\ R_{G}{=}6\Omega \ ^{\text{(Note 1,2)}} \end{array}$	-	52	-	ns		
Turn-Off Delay Time	td _(off)		-	65	-			
Turn-Off Fall Time	tf		-	46	-			
Drain-Source Diode								
Maximum Continuous Drain-Source					-0.4	А		
Diode Forward Current	I _S		-	-	-0.4			
Diode Forward Voltage	V_{SD}	I _S =-1.0A, V _{GS} =0V	-	-0.93	-1.2	V		

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited





TYPICAL CHARACTERISTIC CURVES

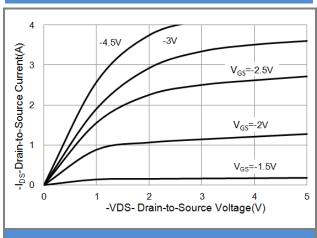


Fig.1 On-Region Characteristics

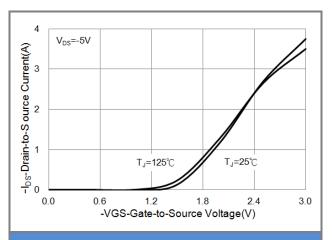


Fig.2 Transfer Characteristics

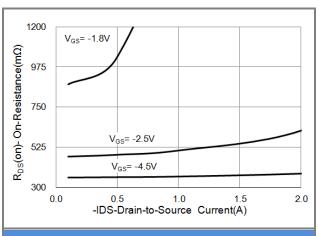


Fig.3 On-Resistance vs. Drain Current

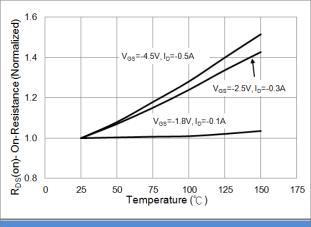


Fig.4 On-Resistance vs. Junction temperature

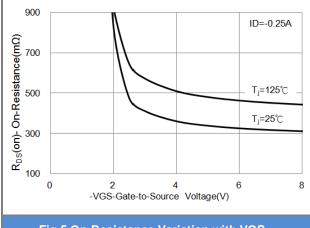
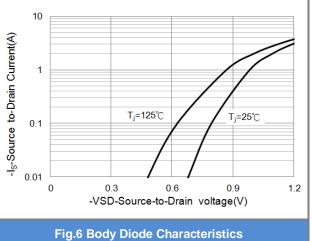


Fig.5 On-Resistance Variation with VGS.







TYPICAL CHARACTERISTIC CURVES

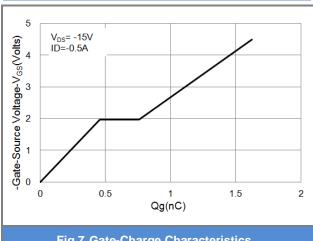


Fig.7 Gate-Charge Characteristics

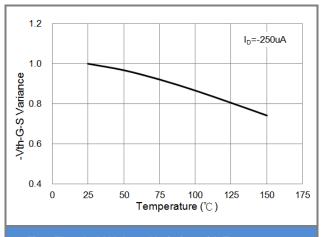
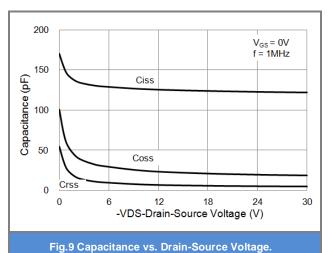


Fig.8 Threshold Voltage Variation with Temperature



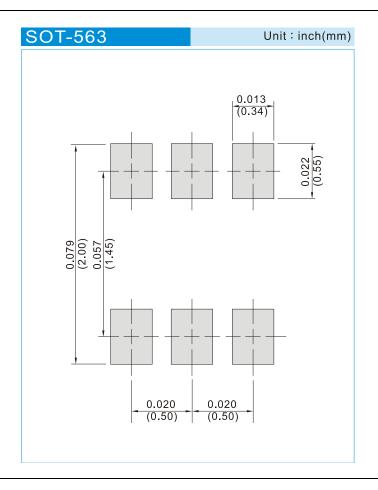




PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJX8805_R1_00002	SOT-563	4K pcs / 7" reel	X05	Halogen free
PJX8805_R2_00002	SOT-563	10K pcs / 13" reel	X05	Halogen free

MOUNTING PAD LAYOUT







Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are
 responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no
 representation or warranty that such applications will be suitable for the specified use without further testing or
 modification.
- The products shown herein are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, transportation equipment, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.